

PC3H4J00000F Series

Mini-flat Half Pitch Package, **AC Input Photocoupler**

*4-channel package type is also available. (model No. PC3Q64QJ000F)



Description

PC3H4J00000F Series contains an IRED optically coupled to a phototransistor.

It is packaged in a 4-pin Mini-flat, half pitch type. Input-output isolation voltage(rms) is 2.5kV.

Collector-emitter voltage is 80V and CTR is 20% to 400% at input current of ±1mA.

Features

- 1. 4-pin Mini-flat Half pitch package (Lead pitch : 1.27mm)
- 2. Double transfer mold package (Ideal for Flow Soldering)
- 3. AC input type
- 4. High collector-emitter voltage (V_{CE} : 80V)
- 5. Isolation voltage between input and output (Viso(rms): 2.5kV)
- 6. Lead-free and RoHS directive compliant

Agency approvals/Compliance

- 1. Recognized by UL1577 (Double protection isolation), file No. E64380 (as model No. PC3H4)
- 2. Approved by VDE, DIN EN60747-5-2^(*) (as an option), file No. 40009162 (as model No. PC3H4)
- 3. Package resin : UL flammability grade (94V-0)

(*) DIN EN60747-5-2 : successor standard of DIN VDE0884

Applications

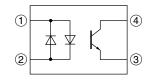
1. Programmable controllers

Notice The content of data sheet is subject to change without prior notice

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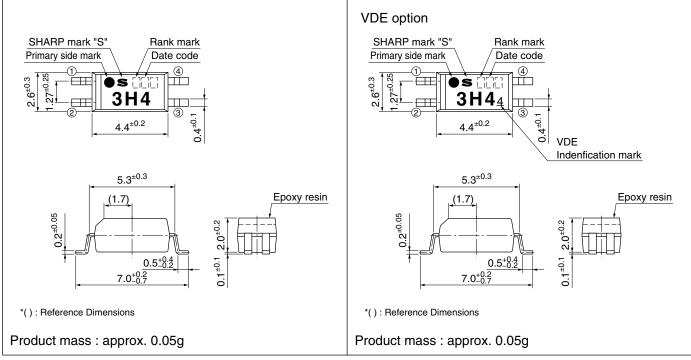
Internal Connection Diagram



- ① Anode / Cathode
- 2 Cathode / Anode
- ③ Emitter
- ④ Collector

Outline Dimensions

(Unit : mm)



Plating material : SnCu (Cu : TYP. 2%)



Date code (2 digit)

	1st o	digit		2nd digit		
		roduction		Month of production		
A.D.			Month	Mark		
1990	А	2002	Р	January	1	
1991	В	2003	R	February	2	
1992	С	2004	S	March	3	
1993	D	2005	Т	April	4	
1994	Е	2006	U	May	5	
1995	F	2007	V	June	6	
1996	Н	2008	W	July	7	
1997	J	2009	Х	August	8	
1998	K	2010	А	September	9	
1999	L	2011	В	October	0	
2000	М	2012	С	November	N	
2001	N	:	:	December	D	

repeats in a 20 year cycle

Country of origin

Japan

Rank mark

Refer to the Model Line-up table

■ Absolute Maximum Ratings

Absolute Maximum Ratings $(T_a=25^{\circ}C)$							
	Parameter	Symbol	Rating	Unit			
t	Forward current	I _F	±50	mA			
Input	*1 Peak forward current	I _{FM}	±1	Α			
Í	Power dissipation	Р	70	mW			
	Collector-emitter voltage	V _{CEO}	80	V			
Output	Emitter-collector voltage	V _{ECO}	6	V			
Out	Collector current	I _C	50	mA			
	Collector power dissipation	P _C	150	mW			
	Fotal power dissipation	P _{tot}	170	mW			
(Operating temperature	T _{opr}	-30 to +100	°C			
S	Storage temperature	T _{stg}	-40 to +125	°C			
*2]	solation voltage	V _{iso (rms)}	2.5	kV			
*3 (Soldering temperature	T _{sol}	260	°C			

*1 Pulse width=100µs, Duty ratio : 0.001 *2 40 to 60%RH, AC for 1 minute *3 For 10s

■ Electro-optical Characteristics

 $(T_a=25^{\circ}C)$

	•						(1a = 20 = 0)	
Parameter		Symbol	Conditions	MIN.	TYP.	MAX.	Unit	
Tamat	Forward voltage		$V_{\rm F}$	$I_F = \pm 20 \text{mA}$	-	1.2	1.4	V
Input	Terminal capacitance		C_t	V=0, f=1kHz	_	30	250	pF
	Collector dark current		I _{CEO}	$V_{CE}=50V, I_{F}=0$	-	-	100	nA
Output	Collector-emitter breakdown voltage		BV _{CEO}	$I_{C}=0.1 \text{mA}, I_{F}=0$	80	-	-	V
	Emitter-collector breakdown voltage		BV _{ECO}	$I_{E}=10\mu A, I_{F}=0$	6	-	-	V
	Collector current		I _C	$I_F=\pm 1$ mA, $V_{CE}=5$ V	0.2	-	4.0	mA
	Collector-emitter saturation voltage		V _{CE (sat)}	$I_F = \pm 20 \text{mA}, I_C = 1 \text{mA}$	-	0.1	0.2	V
Transfer charac- teristics	Isolation resistance		R _{ISO}	DC500V, 40 to 60%RH	5×10 ¹⁰	1×10 ¹¹	-	Ω
	Floating capacitance		C_{f}	V=0, f=1MHz	-	0.6	1.0	pF
	Response time	Rise time	t _r	$V_{CF}=2V$, $I_{C}=2mA$, $R_{I}=100\Omega$	_	4	18	μs
		Fall time	$t_{\rm f}$	$v_{CE}=2v$, $i_{C}=2111A$, $K_{L}=10022$	_	3	18	μs

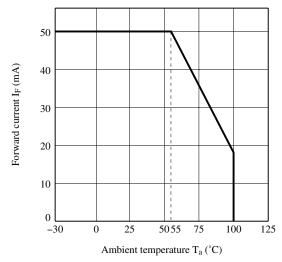


■ Model Line-up

Package		oing ocs/reel	Daalamark	$I_{C} [mA]$ $(I_{F}=\pm 1mA, V_{CE}=5V, T_{a}=25^{\circ}C)$	
DIN EN60747-5-2		Approved	Rank mark		
Model No.	PC3H4J00000F	PC3H4YJ0000F	with or without	0.2 to 4.0	
	PC3H4AJ0000F	PC3H4Y1J000F	А	0.5 to 1.5	

Please contact a local SHARP sales representative to inquire about production status.

Fig.1 Forward Current vs. Ambient Temperature





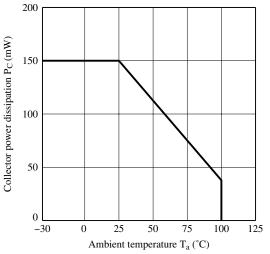


Fig.5 Peak Forward Current vs. Duty Ratio

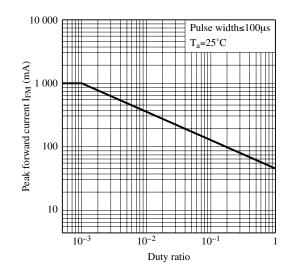


Fig.2 Diode Power Dissipation vs. Ambient Temperature

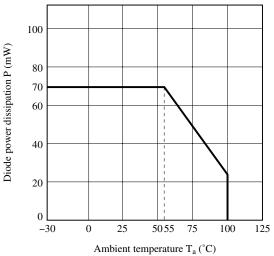


Fig.4 Total Power Dissipation vs. Ambient Temperature

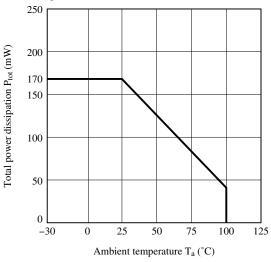


Fig.6 Forward Current vs. Forward Voltage

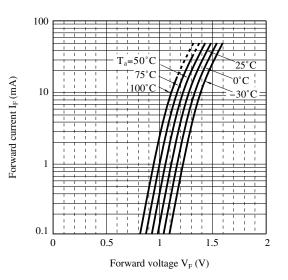
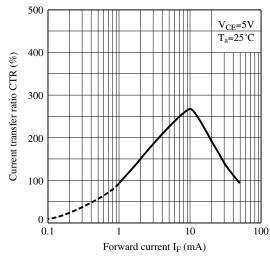
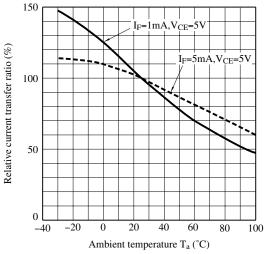




Fig.7 Current Transfer Ratio vs. Forward Current









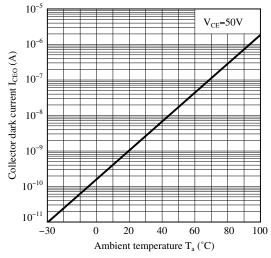


Fig.8 Collector Current vs. Collector-emitter Voltage

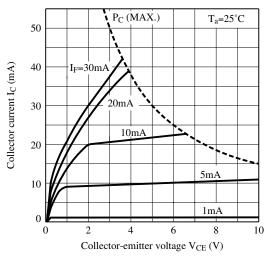
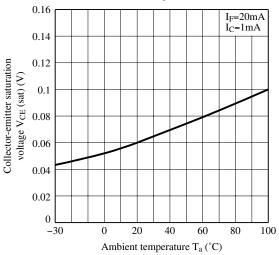


Fig.10 Collector - emitter Saturation Voltage vs. Ambient Temperature





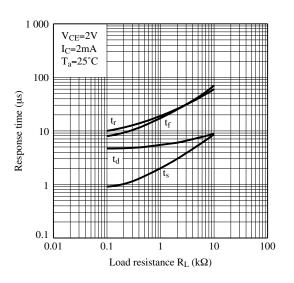
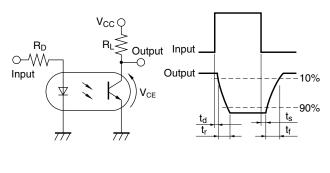


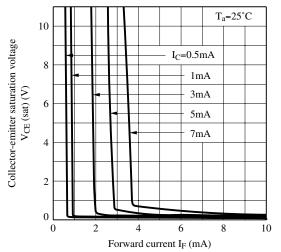


Fig.13 Test Circuit for Response Time



Please refer to the conditions in Fig.12.

Fig.14 Collector-emitter Saturation Voltage vs. Forward Current



Remarks : Please be aware that all data in the graph are just for reference and not for guarantee.



Design Considerations

Design guide

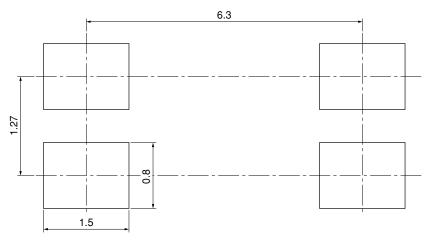
While operating at I_{F} <1.0mA, CTR variation may increase. Please make design considering this fact.

This product is not designed against irradiation and incorporates non-coherent IRED.

Degradation

In general, the emission of the IRED used in photocouplers will degrade over time. In the case of long term operation, please take the general IRED degradation (50% degradation over 5 years) into the design consideration.

• Recommended Foot Print (reference)



(Unit : mm)

☆ For additional design assistance, please review our corresponding Optoelectronic Application Notes.

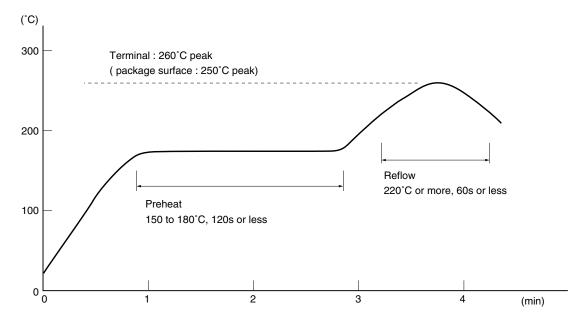


Manufacturing Guidelines

Soldering Method

Reflow Soldering:

Reflow soldering should follow the temperature profile shown below. Soldering should not exceed the curve of temperature profile and time. Please don't solder more than twice.



Flow Soldering :

Due to SHARP's double transfer mold construction submersion in flow solder bath is allowed under the below listed guidelines.

Flow soldering should be completed below 260°C and within 10s. Preheating is within the bounds of 100 to 150°C and 30 to 80s. Please don't solder more than twice.

Hand soldering

Hand soldering should be completed within 3s when the point of solder iron is below 400°C. Please don't solder more than twice.

Other notices

Please test the soldering method in actual condition and make sure the soldering works fine, since the impact on the junction between the device and PCB varies depending on the tooling and soldering conditions.



• Cleaning instructions

Solvent cleaning:

Solvent temperature should be 45°C or below Immersion time should be 3 minutes or less

Ultrasonic cleaning:

The impact on the device varies depending on the size of the cleaning bath, ultrasonic output, cleaning time, size of PCB and mounting method of the device.

Therefore, please make sure the device withstands the ultrasonic cleaning in actual conditions in advance of mass production.

Recommended solvent materials:

Ethyl alcohol, Methyl alcohol and Isopropyl alcohol

In case the other type of solvent materials are intended to be used, please make sure they work fine in actual using conditions since some materials may erode the packaging resin.

Presence of ODC

This product shall not contain the following materials. And they are not used in the production process for this product. Regulation substances : CFCs, Halon, Carbon tetrachloride, 1.1.1-Trichloroethane (Methylchloroform)

Specific brominated flame retardants such as the PBBOs and PBBs are not used in this product at all.

This product shall not contain the following materials banned in the RoHS Directive (2002/95/EC).
•Lead, Mercury, Cadmium, Hexavalent chromium, Polybrominated biphenyls (PBB), Polybrominated diphenyl ethers (PBDE).





■ Package specification

• Tape and Reel package

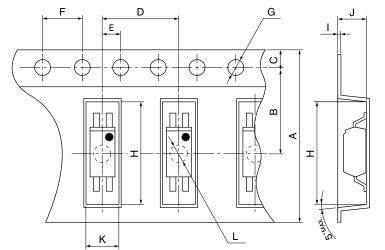
Package materials

Carrier tape : PS

Cover tape : PET (three layer system)

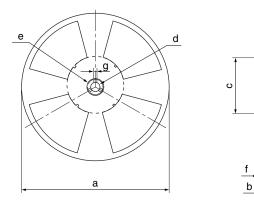
Reel : PS

Carrier tape structure and Dimensions



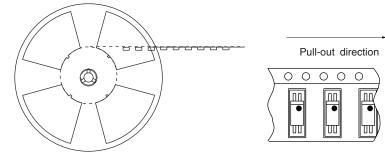
Dimensions List (Unit : mm)						
А	В	С	D	Е	F	G
$12.0^{\pm 0.3}$	$5.5^{\pm 0.1}$	$1.75^{\pm 0.1}$	$8.0^{\pm 0.1}$	$2.0^{\pm 0.1}$	$4.0^{\pm 0.1}$	φ1.5 ^{+0.1}
Н	Ι	J	K	L		
$7.5^{\pm 0.1}$	$0.3^{\pm 0.05}$	2.3 ^{±0.1}	$3.1^{\pm 0.1}$	φ1.6 ^{+0.1} ₋₀		

Reel structure and Dimensions



Dimensio	ns List	(Unit : mm)			
а	b	с	d		
330	$13.5^{\pm 1.5}$	100 ^{±1.0}	13 ^{±0.5}		
e	f	g			
23 ^{±1.0}	$2.0^{\pm 0.5}$	$2.0^{\pm 0.5}$			

Direction of product insertion



[Packing: 3 000pcs/reel]

SHARP

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- --- Personal computers
- --- Office automation equipment
- --- Telecommunication equipment [terminal]
- --- Test and measurement equipment
- --- Industrial control
- --- Audio visual equipment
- --- Consumer electronics

(ii) Measures such as fail-safe function and redundant design should be taken to ensure reliability and safety when SHARP devices are used for or in connection with equipment that requires higher reliability such as:

- --- Transportation control and safety equipment (i.e., aircraft, trains, automobiles, etc.)
- --- Traffic signals
- --- Gas leakage sensor breakers
- --- Alarm equipment
- --- Various safety devices, etc.

(iii) SHARP devices shall not be used for or in connection with equipment that requires an extremely high level of reliability and safety such as:

- --- Space applications
- --- Telecommunication equipment [trunk lines]
- --- Nuclear power control equipment
- --- Medical and other life support equipment (e.g., scuba).

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